VERY HIGH GAIN
PNP POWER DARLINGTON TRANSISTORS

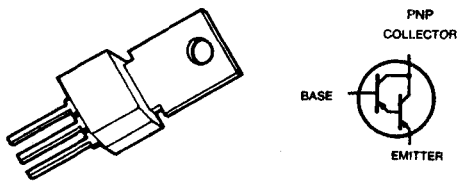
COMPLEMENTARY TO THE D40K SERIES

D41K Series

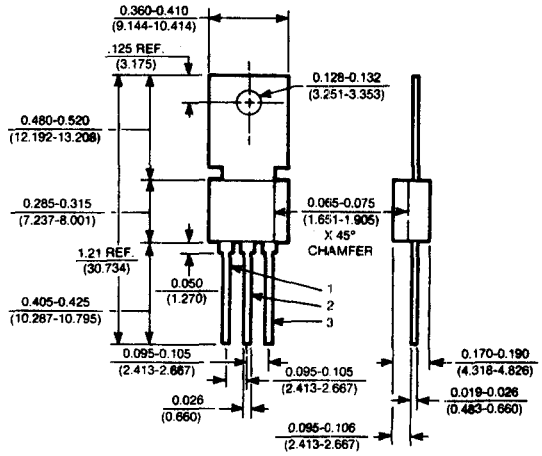
-30 - (-50) VOLTS
-2 AMP, 10 WATTS

Applications:

- Driver
- Regulator
- Touch Switch
- I.C. Driver
- Capacitor Multiplier
- Audio Output
- Relay Substitute
- Oscillator
- Servo-Amplifier



CASE STYLE TO-202
DIMENSIONS ARE IN INCHES AND (MILLIMETERS)



TYPE	TERM. 1	TERM. 2	TERM. 3	TAB
TO-202	EMITTER	BASE	COLLECTOR	COLLECTOR

maximum ratings (T_A = 25°C) (unless otherwise specified)

RATING	SYMBOL	D41K1,3	D41K2,4	UNITS
Collector-Emitter Voltage	V_{CEO}	-30	-50	Volts
Collector-Emitter Voltage	V_{CES}	-13	-13	Volts
Emitter Base Voltage	V_{EBO}	-30	-50	Volts
Collector Current — Continuous Peak(1)	I_C I_{CM}	-2 -3	-2 -3	A A
Base Current — Continuous	I_B	.2	.2	A
Total Power Dissipation @ T_A = 25°C @ T_C = 25°C	P_D	-1.67 -10	-1.67 -10	Watts
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-55 to +150	-55 to +150	°C

thermal characteristics

Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	75	75	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	12.5	12.5	°C/W
Maximum Lead Temperature for Soldering Purposes: ⅛" from Case for 5 Seconds	T_L	260	260	°C

(1) Pulse Test: Pulse Width = 300ms. Duty Cycle ≤ 2%.

electrical characteristics (T_C = 25° C) (unless otherwise specified)

CHARACTERISTIC		SYMBOL	MIN	TYP	MAX	UNIT
off characteristics(1)						
Collector-Emitter Voltage (I_C = 10mA)	D41K1,3 D41K2,4	V_{CEO}	-30 -50	— —	— —	Volts
Collector Cut-off Current (V_{CE} = Rated V_{CES})		I_{CES}	—	—	-.5	μA
Emitter Cutoff Current (V_{EB} = -13V)		I_{EBO}	—	—	-0.1	μA
on characteristics						
DC Current Gain (I_C = -200mA, V_{CE} = -5V)		h_{FE}	10K	—	—	—
(I_C = -1.5A, V_{CE} = -5V) (I_C = -1A, V_{CE} = -5V)	D41K1,2 D41K3,4	h_{FE}	1K 1K	— —	— —	— —
Collector-Emitter Saturation Voltage (I_C = -1.5A, I_B = -3mA) (I_C = -1.0A, I_B = -2mA)	D41K1,2 D41K3,4	$V_{CE(sat)}$	— —	— —	1.5 1.5	Volts V
Base-Emitter Saturation Voltage (I_C = -1.5A, I_B = -3mA) (I_C = -1A, I_B = -2mA)	D41K1,2 D41K3,4	$V_{BE(sat)}$	— —	— —	2.5 2.5	Volts
dynamic characteristics						
Collector Capacitance (V_{CE} = -10V, f = 1MHz)		C_{CBO}	—	9	15	pF
Current-Gain — Bandwidth Product (I_C = -20mA, V_{CE} = -5V)		f_T	—	100	—	MHz

(1) Pulse Test: PW ≤ 300ms Duty Cycle ≤ 2%.

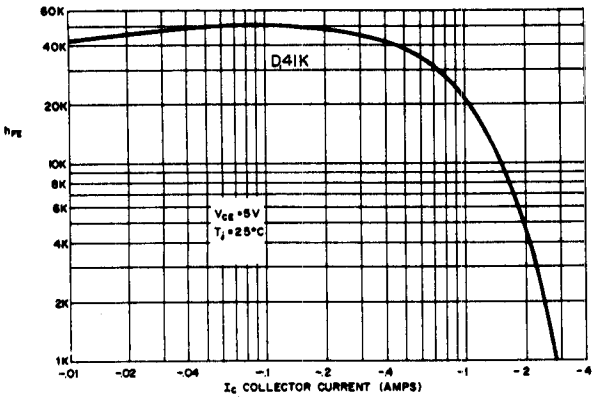


FIG. 1 TYPICAL h_{FE} vs. I_C

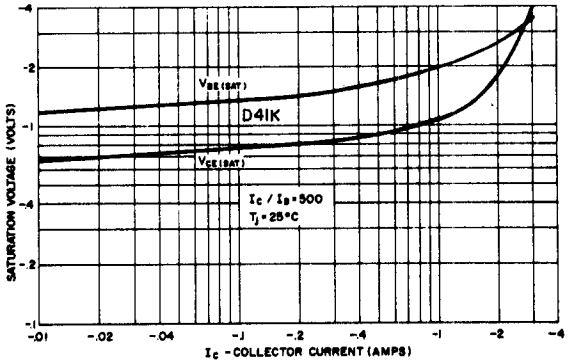


FIG. 2 TYPICAL C_{CBO} vs. VOLTAGE

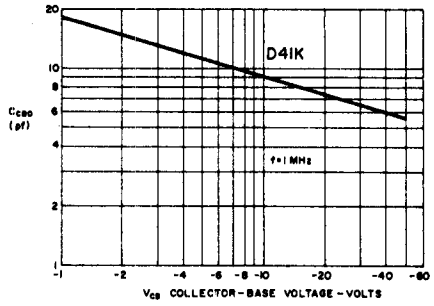


FIG. 3 TYPICAL SATURATION VOLTAGE